NSN 5962-01-519-5543

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
-40.0/+85.0 degrees celsius
Features Provided:
Electrostatic sensitive
Inclosure Material:
Ceramic
Inclosure Configuration:
Pin grid array
Criticality Code Justification:
Cbbl
Product Name:
High-speed 8 k x 16 dual port static ram
Voltage Rating And Type Per Characteristic:
4.5 volts total supply and 5.5 volts total supply
Memory Device Type:
memory bevice Type.
Ram
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Ram
Ram Memory Capacity:
Ram Memory Capacity: 8k x 16
Ram Memory Capacity: 8k x 16 Terminal Type And Quantity:
Ram Memory Capacity: 8k x 16 Terminal Type And Quantity: 84 pin
Ram Memory Capacity: 8k x 16 Terminal Type And Quantity: 84 pin Shelf Life:
Ram Memory Capacity: 8k x 16 Terminal Type And Quantity: 84 pin Shelf Life: N/a
Ram Memory Capacity: 8k x 16 Terminal Type And Quantity: 84 pin Shelf Life: N/a Unit Of Measure:
Ram Memory Capacity: 8k x 16 Terminal Type And Quantity: 84 pin Shelf Life: N/a Unit Of Measure:
Memory Capacity: 8k x 16 Terminal Type And Quantity: 84 pin Shelf Life: N/a Unit Of Measure: Demilitarization:
Ram Memory Capacity: 8k x 16 Terminal Type And Quantity: 84 pin Shelf Life: N/a Unit Of Measure: Demilitarization: Yes - demil/mli